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•	Member of the Texas Instruments Widebus™ Family	DGG OR DL PACKAGE (TOP VIEW)
•	<i>EPIC</i> ™ (Enhanced-Performance Implanted CMOS) Submicron Process	1OE 1 48 1LE 1Q1 2 47 1D1
•	Typical V_{OLP} (Output Ground Bounce) < 0.8 V at V_{CC} = 3.3 V, T_A = 25°C	1Q2 3 46 1D2 GND 4 45 1 GND
•	Typical V_{OHV} (Output V_{OH} Undershoot) > 2 V at V_{CC} = 3.3 V, T_A = 25°C	1Q3
•	Power Off Disables Outputs, Permitting Live Insertion	$V_{CC} \begin{bmatrix} 1 \\ 7 \end{bmatrix}$ 42 $\begin{bmatrix} 1 \\ 42 \end{bmatrix}$ V_{CC} 1Q5 $\begin{bmatrix} 1 \\ 41 \end{bmatrix}$ 1D5
•	Supports Mixed-Mode Signal Operation (5-V Input and Output Voltages With 3.3-V V _{CC})	1Q6
•	ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)	1Q8
•	Latch-Up Performance Exceeds 250 mA Per JESD 17	GND
•	Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors	V _{CC} 118 31 V _{CC} 2Q5 119 30 2D5 2Q6 20 29 2D6
•	Package Options Include Plastic 300-mil Shrink Small-Outline (DL) and Thin Shrink Small-Outline (DGG) Packages	GND
desc	ription	2 OE [24 25] 2LE

This 16-bit transparent D-type latch is designed for 1.65-V to 3.6-V V_{CC} operation.

The SN74LVCH16373A is particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers. It can be used as two 8-bit latches or one 16-bit latch. When the latch-enable (LE) input is high, the Q outputs follow the data (D) inputs. When LE is taken low, the Q outputs are latched at the levels set up at the D inputs.

A buffered output-enable (\overline{OE}) input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or the high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without interface or pullup components.

OE does not affect internal operations of the latch. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

Inputs can be driven from either 3.3-V or 5-V devices. This feature allows the use of these devices as translators in a mixed 3.3-V/5-V system environment.

To ensure the high-impedance state during power up or power down, $\overline{\sf OE}$ should be tied to ${\sf V}_{\sf CC}$ through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

The SN74LVCH16373A is characterized for operation from –40°C to 85°C.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

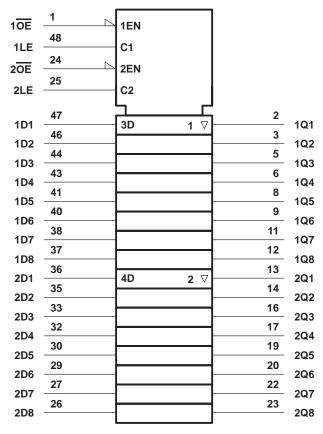
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FUNCTION TABLE

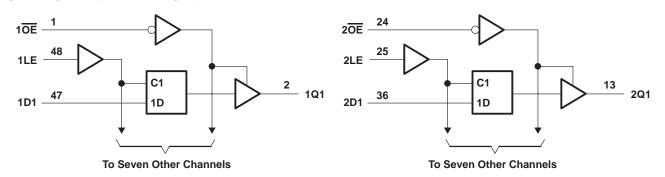
	INPUTS	OUTPUT	
OE	LE	D	Q
L	Н	Н	Н
L	Н	L	L
L	L	Χ	Q ₀
Н	Χ	Χ	Z

logic symbol†



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)





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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}	
Input voltage range, V _I (see Note 1)	
Voltage range applied to any output in the high-impedance or power-off	state, V _O
(see Note 1)	
Voltage range applied to any output in the high or low state, VO	
(see Notes 1 and 2)	-0.5 V to V_{CC} + 0.5 V
Input clamp current, I _{IK} (V _I < 0)	
Output clamp current, I_{OK} ($V_O < 0$)	
Continuous output current, I _O	±50 mA
Continuous current through each V _{CC} or GND	±100 mA
Package thermal impedance, θ _{JA} (see Note 3): DGG package	89°C/W
DL package	94°C/W
Storage temperature range, T _{stg}	

NOTES: 1. The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

- 2. The value of V_{CC} is provided in the recommended operating conditions table.
- 3. The package thermal impedance is calculated in accordance with JESD 51.

recommended operating conditions (see Note 4)

			MIN	MAX	UNIT	
V/0.0	Supply voltage	Operating	1.65	3.6	V	
VCC	Supply voltage	Data retention only	1.5		V	
	High-level input voltage	V _{CC} = 1.65 V to 1.95 V	0.65 × V _{CC}			
VIH		V _{CC} = 2.3 V to 2.7 V	1.7		V	
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2			
		V _{CC} = 1.65 V to 1.95 V		0.35 × V _{CC}		
V_{IL}	Low-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.7	V	
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$		0.8		
٧ _I	Input voltage		0	5.5	V	
\/ -	Output voltage	High or low state	0	VCC	٧	
۷O		3 state	0	5.5		
	High-level output current	V _{CC} = 1.65 V		-4		
lou		V _{CC} = 2.3 V		-8	A	
ЮН		V _{CC} = 2.7 V		-12	mA	
		V _{CC} = 3 V		-24		
		V _{CC} = 1.65 V		4		
lou	Low lovel output ourrent	V _{CC} = 2.3 V		8	m A	
lOL	Low-level output current	V _{CC} = 2.7 V		12	mA	
		V _{CC} = 3 V		24		
Δt/Δν	Input transition rise or fall rate	-	0	10	ns/V	
TA	Operating free-air temperature		-40	85	°C	

NOTE 4: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

SN74LVCH16373A **16-BIT TRANSPARENT D-TYPE LATCH WITH 3-STATE OUTPUTS**

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITION	IS	Vcc	MIN	TYP	MAX	UNIT	
	I _{OH} = -100 μA		1.65 V to 3.6 V	V _{CC} -0.2				
	I _{OH} = -4 mA	$I_{OH} = -4 \text{ mA}$						
Vari	I _{OH} = -8 mA	2.3 V	1.7			v		
VOH	I _{OH} = -12 mA		2.7 V	2.2			٧	
	IOH = -12 IIIA		3 V	2.4				
	I _{OH} = -24 mA		3 V	2.2				
	I _{OL} = 100 μA		1.65 V to 3.6 V			0.2		
	I _{OL} = 4 mA		1.65 V			0.45		
VOL	I _{OL} = 8 mA		2.3 V			0.7	V	
	I _{OL} = 12 mA	2.7 V			0.4			
	I _{OL} = 24 mA		3 V			0.55		
lį	V _I = 0 to 5.5 V		3.6 V			±5	μΑ	
	V _I = 0.58 V	1.65 V	‡			μА		
	V _I = 1.07 V	1.05 V	‡					
	V _I = 0.7 V	2.3 V	45					
I _{I(hold)}	V _I = 1.7 V	2.5 V	-45					
	V _I = 0.8 V	3 V	75					
	V _I = 2 V	3 V	-75					
	V _I = 0 to 3.6 V§		3.6 V			±500		
l _{off}	V_I or $V_O = 5.5 V$		0			±10	μΑ	
I _{OZ}	V _O = 0 to 5.5 V		3.6 V			±10	μΑ	
laa	V _I = V _{CC} or GND	10 0	3.6 V			20	^	
Icc	$3.6 \text{ V} \leq \text{V}_{\text{I}} \leq 5.5 \text{ V}^{\P}$	IO = 0	3.6 V			20	μΑ	
ΔlCC	One input at V _{CC} – 0.6 V, Other inputs at V _{CC} or GND					500	μΑ	
C _i	V _I = V _{CC} or GND		3.3 V		5		pF	
Co	V _O = V _{CC} or GND		3.3 V		6.5		pF	

timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figures 1 through 3)

		V _{CC} = 1.8 V ± 0.15 V		V _{CC} = 1.8 V ± 0.15 V		V _{CC} = 2.7 V		V _{CC} = 3.3 V ± 0.3 V		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _W	Pulse duration, LE high	‡		‡		3.3		3.3		ns
t _{su}	Setup time, data before LE↓	‡		‡		1.7		1.7		ns
t _h	Hold time, data after LE \downarrow	‡		‡		1.2		1.2		ns

[‡] This information was not available at the time of publication.



[†] All typical values are at V_{CC} = 3.3 V, T_A = 25°C. ‡ This information was not available at the time of publication.

[§] This is the bus-hold maximum dynamic current required to switch the input from one state to another.

[¶] This applies in the disabled state only.

switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figures 1 through 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = ± 0.1		V _{CC} =	2.5 V 2 V	VCC =	2.7 V	V _{CC} =	3.3 V 3 V	UNIT
	(INFOT)	(0011-01)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
4 .	D	Q	†	†	†	†		4.9	1.6	4.2	ns
^t pd	LE		†	†	†	†		5.3	2.1	4.6	115
t _{en}	ŌĒ	Q	†	†	†	†		5.7	1.3	4.7	ns
t _{dis}	ŌĒ	Q	†	†	†	†		6.3	2.5	5.9	ns

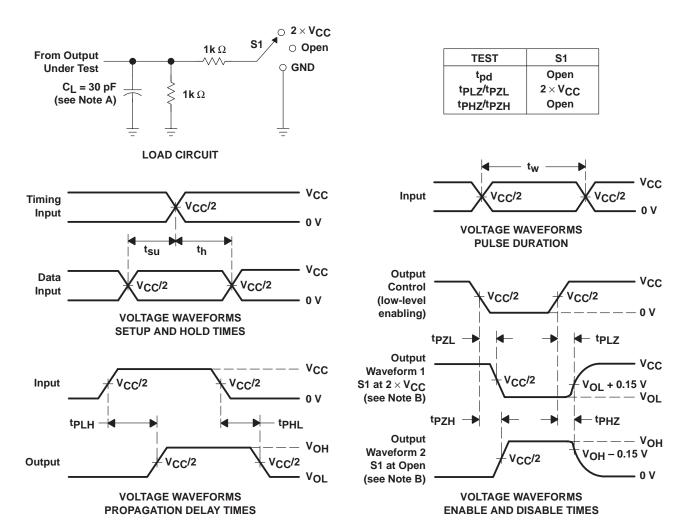
[†] This information was not available at the time of publication.

operating characteristics, $T_A = 25^{\circ}C$

	PARAMETER		TEST CONDITIONS	V _{CC} = 1.8 V ± 0.15 V	V _{CC} = 2.5 V ± 0.2 V	V _{CC} = 3.3 V ± 0.3 V	UNIT
			CONDITIONS	TYP	TYP	TYP	1 1
Const	Power dissipation capacitance	Outputs enabled	f = 10 MHz	†	†	39	pF
C _{pd}	per latch	Outputs disabled	1 = 10 MH2	†	†	6	pr pr

[†] This information was not available at the time of publication.

PARAMETER MEASUREMENT INFORMATION V_{CC} = 1.8 V \pm 0.15 V

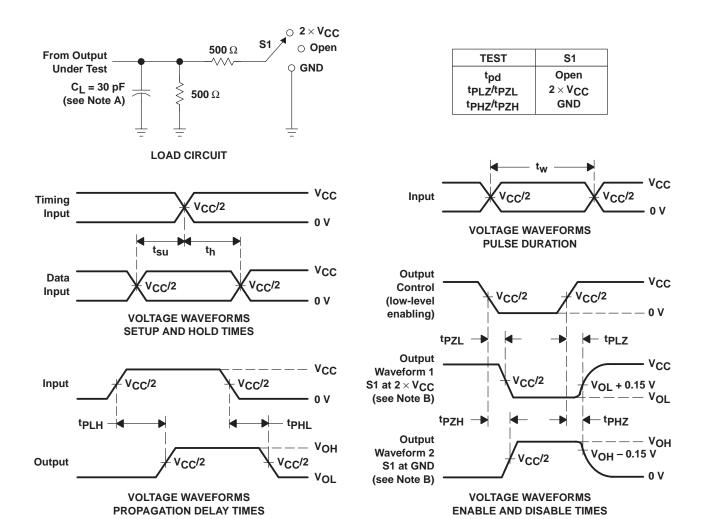


- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_r \leq$ 2 ns, $t_f \leq$ 2 ns.
 - D. The outputs are measured one at a time with one transition per measurement.
 - E. tpLz and tpHz are the same as tdis.
 - F. tpzL and tpzH are the same as ten.
 - G. tpLH and tpHL are the same as tpd.

Figure 1. Load Circuit and Voltage Waveforms



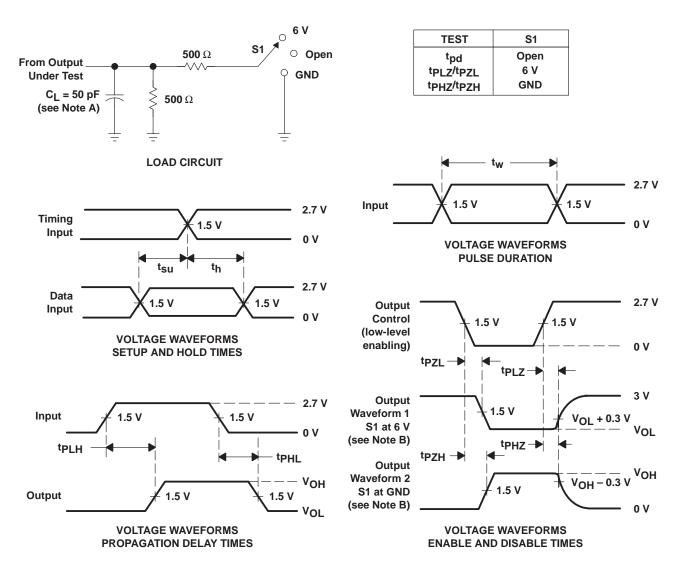
PARAMETER MEASUREMENT INFORMATION $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$



- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_f \leq$ 2 ns. $t_f \leq$ 2 ns.
 - D. The outputs are measured one at a time with one transition per measurement.
 - E. tpLz and tpHz are the same as tdis.
 - F. tpzL and tpzH are the same as ten.
 - G. tpLH and tpHL are the same as tpd.

Figure 2. Load Circuit and Voltage Waveforms

PARAMETER MEASUREMENT INFORMATION V_{CC} = 2.7 V AND 3.3 V \pm 0.3 V



- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_Q = 50 \Omega$, $t_f \leq$ 2.5 ns, $t_f \leq$ 2.5 ns.
 - D. The outputs are measured one at a time with one transition per measurement.
 - E. tpLz and tpHz are the same as tdis.
 - F. tpzL and tpzH are the same as ten.
 - G. t_{PLH} and t_{PHL} are the same as t_{pd} .

Figure 3. Load Circuit and Voltage Waveforms



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